AUTOMOTIVE

RoHS

COMPLIANT HALOGEN

**FREE** 



### Vishay Semiconductors

# Ultrafast Rectifier, 2 A FRED Pt®



#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 A			
V <sub>R</sub>	200 V			
V <sub>F</sub> at I <sub>F</sub>	0.66 V			
t <sub>rr</sub> typ.	24 ns			
T <sub>J</sub> max.	175 °C			
Package	SMB (DO-214AA)			
Circuit configuration	Single			

#### **FEATURES**

- Ultrafast recovery time, reduced Q<sub>rr</sub> and soft recovery
- 175 °C maximum operating junction temperature
- Specific for output and snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and fast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, output operation, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element.

#### **MECHANICAL DATA**

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>L</sub> = 150 °C <sup>(1)</sup>	2	Δ.
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 6 ms square pulse	70	Α
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stq</sub>		-65 to +175	°C

#### Note

(1) Mounted on PCB with 6 mm x 3.5 mm lands

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	200	-	-	
England voltage	V <sub>F</sub>	I <sub>F</sub> = 2 A	-	0.84	0.9	V
Forward voltage		I <sub>F</sub> = 2 A, T <sub>J</sub> = 150 °C	-	0.66	0.7	
December Inches a comment	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	=		2	
Reverse leakage current		<sup>I</sup> R	$T_J = 150  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	20
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF
Critical rate if rise of reverse voltage	$dV/dt_{\tau}$		-	-	10 000	V/µs



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	24	-	
			$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		27	-	
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	23	ns
	T <sub>J</sub> = 25 °C		-	21	-		
		T <sub>J</sub> = 125 °C		-	26	-	
Dools recovery assured	Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 2 A dI <sub>F</sub> /dt = 200 A/μs	-	2.7	-	Α
Feak recovery current		T <sub>J</sub> = 125 °C	$V_{R} = 100 \text{ V}$	-	3.4	-	
Develope vegevent charge	T <sub>J</sub> = 25 °C		-	28	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	43	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction to mount	R <sub>thJM</sub> <sup>(1)</sup>		-	-	17	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub> <sup>(1)</sup>		-	-	80	C/VV
Approximate Weight				0.1		g
Approximate weight				0.003		OZ.
Marking device		Case style SMB (DO-214AA)		21	12	

#### Note

 $<sup>^{(1)}</sup>$  Units mounted on PCB 6 mm x 3.5 mm land areas

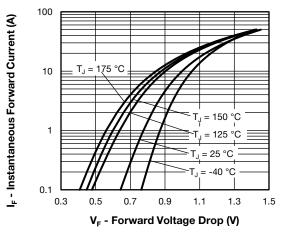


Fig. 1 - Typical Forward Voltage Drop Characteristics

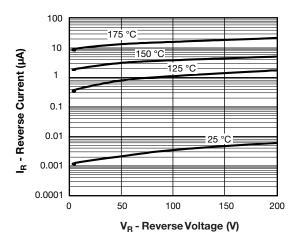


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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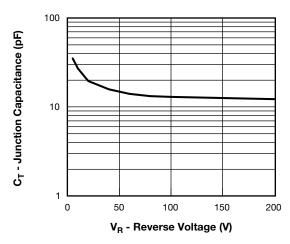


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

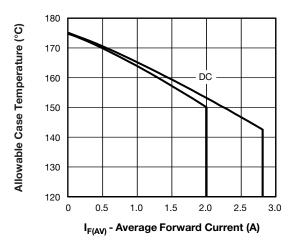


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

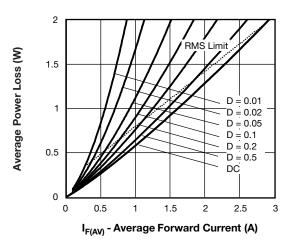


Fig. 5 - Forward Power Loss Characteristics

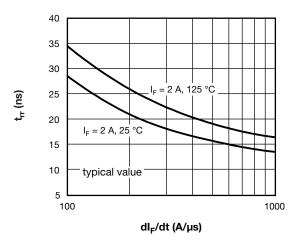


Fig. 6 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

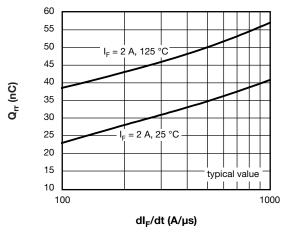
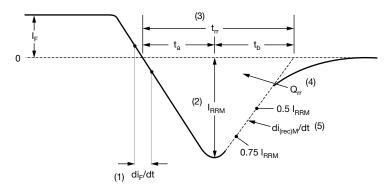


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt



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- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (2)  $I_{RRM}$  peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{r}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (5)  $di_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION (Example)				
PREFERRED P/N	PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-2EGH02HM3_A/I	I	3200	13"diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95401			
Part marking information	www.vishay.com/doc?95472			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?96021			

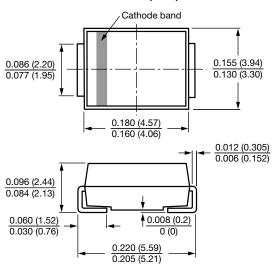


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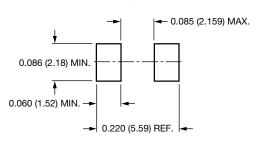
### **SMB**

### **DIMENSIONS** in inches (millimeters)

### DO-214AA (SMB)



### **Mounting Pad Layout**





## **Legal Disclaimer Notice**

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